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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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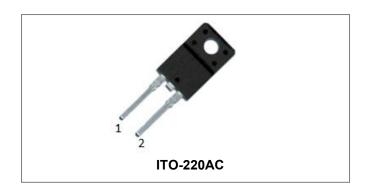




# RoHS



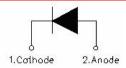
# **SURF860 ULTRAFAST RECTIFIER**



### **Features**

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

### **Circuit Diagram**



### **Applications**

- Switching Power Supply
- Power Switching Circuits
- General Purpose

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	600	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=90°C, rectangular wave form	8	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	80	Α

#### **Electrical Characteristics:**

Characteristics	acteristics Symbol Condition		Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@8A, Pulse, T <sub>J</sub> = 25°C	1.20	2.2	V
	V <sub>F2</sub>	@8A, Pulse, T <sub>J</sub> = 125°C	1.05	2.0	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25°C	0.03	2	μΑ
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125^{\circ}C$	5	500	μΑ
Reverse Recovery Time	t <sub>rr</sub>	t <sub>rr</sub> I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>rm</sub> =250mA		50	ns
RSM Isolation Voltage (t=1.0 second,R.H.< =30%,		Clip mouting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	-	4500	
T <sub>A</sub> =25°C)	V <sub>1so</sub>	Clip mouting, the epoxy body is inside the heatsink	-	3500	V
		Screw mounting, the epoxy body is inside the heatsink	-	1500	

<sup>\*</sup> Pulse width < 300 μs, duty cycle < 2%

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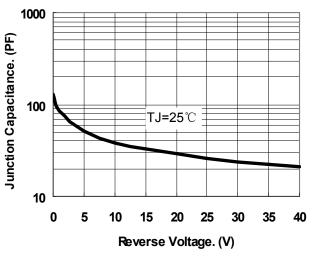




# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> Jc	DC operation	3	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	ITO-220AC			

## **Ratings and Characteristics Curves**



**Fig.1-Typical Junction Capacitance** 

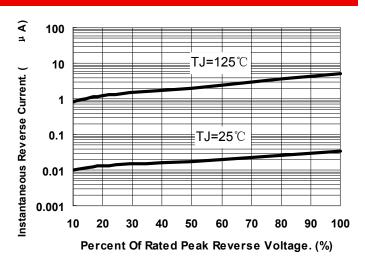


Fig.2-Typical Reverse Characteristics

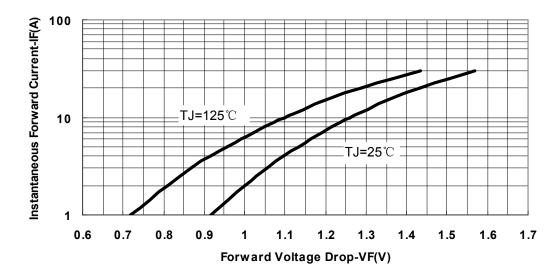


Fig.3-Typical Forward Voltage Drop Characteristics

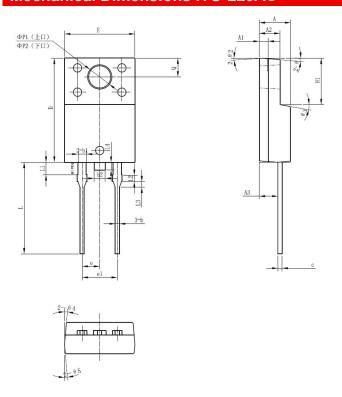
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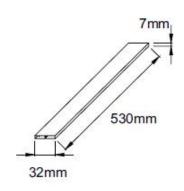


### **Mechanical Dimensions ITO-220AC**

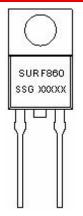


CVMPOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
С	0.50	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е	-	2.55	-	
e1	5.00	5.10	5.16	
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
L4	_	1.10	1.50	
<b>ΦP1(</b> 上口)	3.30	3.50	3.70	
<b>ΦP2</b> (下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

### **Tube Specification**



# **Marking Diagram**



Where XXXXX is YYWWL

SUR = Device Type
F = Package type
8 = Forward Current (8A)
60 = Reverse Voltage (600V)
SSG = SSG
- YSG

YY = Year WW = Week L = Lot Number

**Cautions:** Molding resin
Epoxy resin UL:94V-0

## **Ordering Information**

Device	Package	Shipping	
SURF860	ITO-220AC (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification

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